



BDY26, 183 T2
BDY27, 184 T2
BDY28, 185 T2

NPN SILICON TRANSISTORS, DIFFUSED MESA

LF Large Signal Power Amplification
 High Current Fast Switching

ABSOLUTE MAXIMUM RATINGS

Symbol	Ratings		Value	Unit	
V_{CEO}	Collector-Emitter Voltage	BDY26, 183T2	180	V	
		BDY27, 184T2	200		
		BDY28, 185T2	250		
V_{CBO}	Collector-Base Voltage	BDY26, 183T2	300	V	
		BDY27, 184T2	400		
		BDY28, 185T2	500		
V_{EBO}	Emitter-Base Voltage	BDY26, 183T2 BDY27, 184T2 BDY28, 185T2	10	V	
I_C	Collector Current	BDY26, 183T2 BDY27, 184T2 BDY28, 185T2	6	A	
I_B	Base Current	BDY26, 183T2 BDY27, 184T2 BDY28, 185T2	3	A	
P_{TOT}	Power Dissipation	@ $T_C = 25^\circ$	BDY26, 183T2 BDY27, 184T2 BDY28, 185T2	87.5	Watts
T_J	Junction Temperature		BDY26, 183T2 BDY27, 184T2	200	$^\circ C$
T_{Stg}	Storage Temperature		BDY28, 185T2	-65 to +200	

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THERMAL CHARACTERISTICS

Symbol	Ratings	Value	Unit
R_{thJ-C}	Thermal Resistance, Junction to Case	BDY26, 183T2 BDY27, 184T2 BDY28, 185T2	2 °C/W

ELECTRICAL CHARACTERISTICS

TC=25°C unless otherwise noted

Symbol	Ratings	Test Condition(s)	Min	Typ	Mx	Unit	
$V_{CEO(BR)}$	Collector-Emitter Breakdown Voltage (*)	$I_C=50\text{ mA}, I_B=0$	BDY26, 183T2	180	-	-	V
			BDY27, 184T2	200	-	-	
			BDY28A, 185T2A	250	-	-	
			BDY28B, 185T2B	250	-	-	
			BDY28C, 185T2C	220	-	-	
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage (*)	$I_C=3\text{ mA}$	BDY26, 183T2	300	-	-	V
			BDY27, 184T2	400	-	-	
			BDY28, 185T2	500	-	-	
I_{CEO}	Collector-Emitter Cutoff Current	$V_{CE}=180\text{ V}$	BDY26	-	-	1.0	mA
		$V_{CE}=200\text{ V}$	BDY27	-	-		
		$V_{CE}=250\text{ V}$	BDY28	-	-		
I_{EBO}	Emitter-Base Cutoff Current	$V_{EB}=10\text{ V}$	BDY26, 183T2 BDY27, 184T2 BDY28, 185T2	-	-	1.0	mA
I_{CES}	Collector-Emitter Cutoff Current	$V_{CE}=250\text{ V}$ $V_{BE}=0\text{ V}$	BDY26, 183T2	-	-	1.0	mA
		$V_{CE}=300\text{ V}$ $V_{BE}=0\text{ V}$	BDY27, 184T2	-	-		
		$V_{CE}=400\text{ V}$ $V_{BE}=0\text{ V}$	BDY28, 185T2	-	-		

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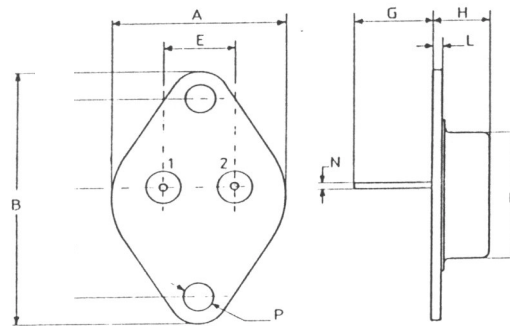
Symbol	Ratings	Test Condition(s)	Min	Typ	Mx	Unit	
$V_{CE(SAT)}$	Collector-Emitter saturation Voltage (*)	$I_C=2.0\text{ A}, I_B=0.25\text{ A}$	BDY26, 183T2	-	-	0.6	V
			BDY27, 184T2	-	-		
			BDY28, 185T2	-	-		
$V_{BE(SAT)}$	Base-Emitter Voltage (*)	$I_C=2.0\text{ A}, I_B=0.25\text{ A}$	BDY26, 183T2	-	-	1.2	V
			BDY27, 184T2	-	-		
			BDY28, 185T2	-	-		
h_{21E}	Static Forward Current transfer ratio (*)	$V_{CE}=4\text{ V}, I_C=1\text{ A}$	A	-	55	-	-
			B	-	65	-	
			C	-	90	-	
		$V_{CE}=4\text{ V}, I_C=2\text{ A}$	A	15	20	45	
			B	30	45	90	
			C	75	82	100	
f_T	Transition Frequency	$V_{CE}=15\text{ V}, I_C=0.5\text{ A}, f=10\text{ MHz}$	BDY26, 183T2 BDY27, 184T2 BDY28, 185T2	10	-	-	MHz
$t_d + t_r$	Turn-on time	$I_C=5\text{ A}, I_B=1\text{ A}$	BDY26, 183T2 BDY27, 184T2 BDY28, 185T2	-	0.3	0.5	μs
$t_s + t_f$	Turn-off time	$I_C=5\text{ A}, I_{B1}=1\text{ A}, I_{B2}=-0.5\text{ A}$	BDY26, 183T2 BDY27, 184T2 BDY28, 185T2	-	1.5	2.0	μs

(*) Pulse Width $\approx 300\ \mu\text{s}$, Duty Cycle $\angle 2.0\%$

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MECHANICAL DATA CASE TO-3

DIMENSIONS		
	mm	inches
A	25,45	1
B	38,8	1,52
C	30,09	1,18
D	17,11	0,67
E	9,78	0,39
G	11,09	0,45
H	8,33	0,34
L	1,62	0,06
M	19,43	0,79
N	1	0,04
P	4,08	0,16



Pin 1 :	Base
Pin 2 :	Collector
Case :	Emitter